Initial Release

Six Pair N- and P-Channel Enhancement-Mode MOSFET

Features

- Six N- and P-channel MOSFET pairs
- Integrated gate-source resistor
- Integrated gate-source zener diode
- Low threshold
- Low on-resistance
- Low input capacitance
- Fast switching speeds
- Free from secondary breakdowns
- Low input and output leakage

Application

- High voltage pulsers
- Amplifiers
- Buffers
- Piezoelectric transducer drivers
- General purpose line drivers
- Logic level interfaces

General Description

The Supertex TC7320FG consists of a six pairs of high voltage low threshold N-channel and P-channel MOSFETs in a 32-lead LQFP package. All the MOSFETs have integrated gate-source resistors and gate-source zener diode clamps which are desired for high voltage pulser applications. These low threshold enhancement-mode (normally-off) transistors utilize an advanced lateral DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces devices with the power handling capabilities of bipolar transistors and with the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, these devices are free from thermal runaway and thermally induced secondary breakdown.

Supertex's lateral DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Absolute Maximum Ratings*

Drain-to-Source Voltage	BV_{DSS}
Drain-to-Gate Voltage	BV_{DGS}
Operating and Storage Temperature	-55°C to +150°C
Soldering Temperature*	300°C

**Distance of 1.6mm from case for 10 seconds.*

Ordering Information

Order Number / Package	BV_{DSS} / BV_{DGS}		$R_{DS(ON)}$ (max)	
32-Lead LQFP	**N-Channel**	**P-Channel**	**N-Channel**	**P-Channel**
TC7320FG	200V	-200V	20Ω	20Ω
TC7320FG-G*	200V	-200V	20Ω	20Ω

**"Green" certified package*

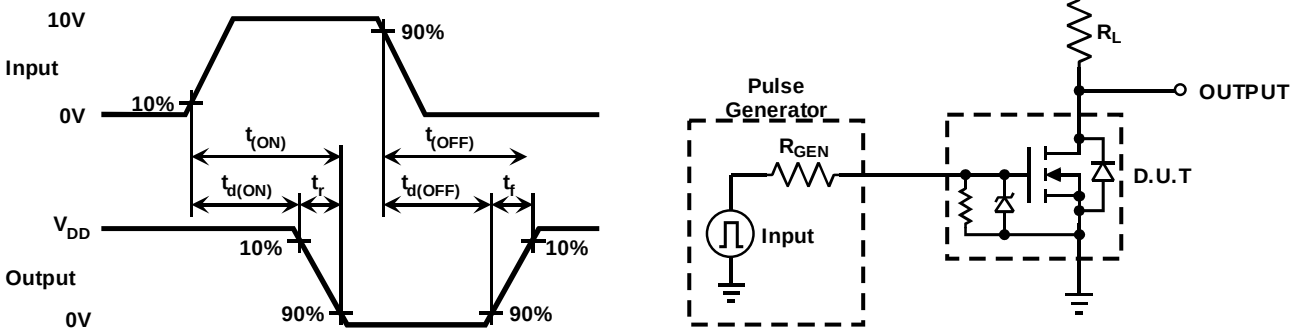
A080405

N-Channel Electrical Characteristics *(at T_A=25°C unless otherwise specified)*

Symbol	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSS}	Drain-to-Source Breakdown Voltage	200			V	V_{GS}=0V, I_D=1mA
$V_{GS(th)}$	Gate Threshold Voltage		0.4		V	V_{GS}=V_{DS}, I_D=1mA
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with Temperature			-4.5	mV/°C	V_{GS}=V_{DS}, I_D=1mA
R_{GS}	Gate-Source Shunt Resistor	0.9		8.0	KΩ	I_{GS}=100µA
ΔR_{GS}	Change in R_{GS} with Temperature			TBD	%/°C	I_{GS}=100µA
Vz_{GS}	Gate-Source Zener Voltage	10		18	V	I_{GS}=2.0mA
ΔVz_{GS}	Change in Vz_{GS} with Temperature			TBD	mV/°C	I_{GS}=2.0mA
I_{DSS}	Zero Gate Voltage Drain Current			10	µA	V_{GS}=0V, V_{DS}=Max Rating
				1.0	mA	V_{GS}=0V, V_{DS}=0.8 Max Rating, T_A=125°C
$I_{D(ON)}$	On-State Drain Current	1.0			A	V_{GS}=10V, V_{DS}=25V
$R_{DS(ON)}$	Static Drain-to-Source ON-State Resistance			20	Ω	V_{GS}=10V, I_D=150mA
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with Temperature			1.0	%/°C	V_{GS}=10V, I_D=150mA
G_{FS}	Forward Transconductance		150		mmho	V_{DS}=25V, I_D=200mA
C_{ISS}	Input Capacitance			150	pF	V_{GS}=0V, V_{DS}=25V f=1MHz
C_{OSS}	Common Source Output Capacitance			75		
C_{RSS}	Reverse Transfer Capacitance			25		
$t_{d(ON)}$	Turn-ON Delay Time			12	ns	V_{DD}=25V, I_D=500mA R_{GEN}=25 Ω
t_r	Rise Time			15		
$t_{d(OFF)}$	Turn-Off Delay Time			25		
t_f	Fall Time			40		
V_{SD}	Diode Forward Voltage Drop			1.8	V	V_{GS}=0V, I_{SD}=0.5A
t_{rr}	Reverse Recovery Time		300		ns	V_{GS}=0V, I_{SD}=0.5A

Notes:
1) All DC parameters 100% tested at 25°C unless otherwise stated. (Pulsed test: 300µs pulse at 2% duty cycle.)
2) All AC parameters sample tested.

N-Channel Switching Waveforms and Test Circuit

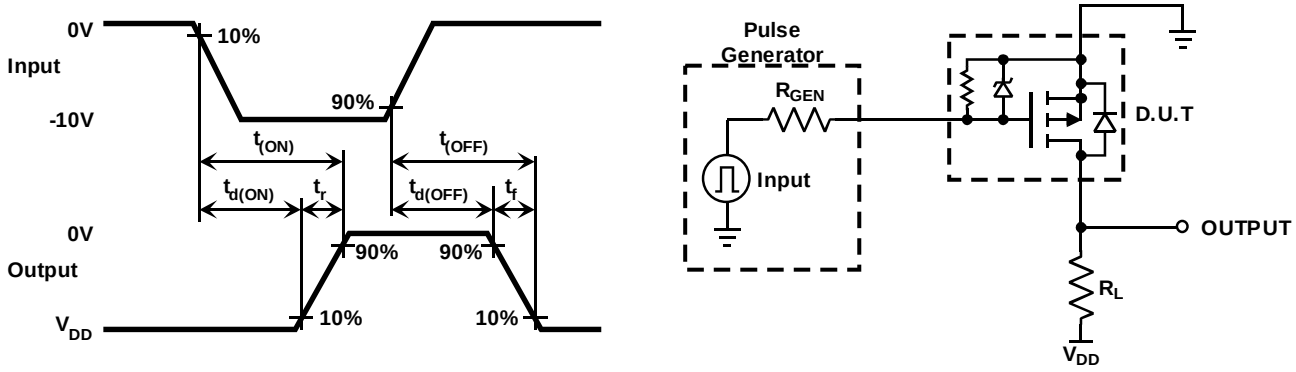


P-Channel Electrical Characteristics *(at T_A=25°C unless otherwise specified)*

Symbol	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSS}	Drain-to-Source Breakdown Voltage	-200			V	V_{GS}=0V, I_D=-1mA
$V_{GS(th)}$	Gate Threshold Voltage		-2.3		V	V_{GS}=V_{DS}, I_D=-1mA
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with Temperature			4.5	mV/°C	V_{GS}=V_{DS}, I_D=-1mA
R_{GS}	Gate-Source Shunt Resistor	0.9		8.0	KΩ	I_{GS}=-100µA
ΔR_{GS}	Change in R_{GS} with Temperature			TBD	%/°C	I_{GS}=-100µA
Vz_{GS}	Gate-Source Zener Voltage	10		18	V	I_{GS}=-2.0mA
$\Delta V_{GS(th)}$	Change in Vz_{GS} with Temperature			TBD	mV/°C	I_{GS}=-2.0mA
I_{DSS}	Zero Gate Voltage Drain Current			-10	µA	V_{GS}=0V, V_{DS}=Max Rating
				-1.0	mA	V_{GS}=0V, V_{DS}=0.8 Max Rating, T_A=125°C
$I_{D(ON)}$	On-State Drain Current	-1.0			A	V_{GS}=-10V, V_{DS}=-25V
$R_{DS(ON)}$	Static Drain-to-Source ON-State Resistance			20	Ω	V_{GS}=-10V, I_D=-150mA
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with Temperature			1.0	%/°C	V_{GS}=-10V, I_D=-150mA
G_{FS}	Forward Transconductance		150		mmho	V_{DS}=-25V, I_D=-200mA
C_{ISS}	Input Capacitance			200	pF	V_{GS}=0V, V_{DS}=-25V f=1MHz
C_{OSS}	Common Source Output Capacitance			100		
C_{RSS}	Reverse Transfer Capacitance			35		
$t_{d(ON)}$	Turn-ON Delay Time			15	ns	V_{DD}=-25V, I_D=-500mA R_{GEN}=25 Ω
t_r	Rise Time			20		
$t_{d(OFF)}$	Turn-Off Delay Time			35		
t_f	Fall Time			30		
V_{SD}	Diode Forward Voltage Drop			-1.8	V	V_{GS}=0V, I_{SD}=-0.5A
t_{rr}	Reverse Recovery Time		300		ns	V_{GS}=0V, I_{SD}=-0.5A

Notes:
1) All DC parameters 100% tested at 25°C unless otherwise stated. (Pulsed test: 300µs pulse at 2% duty cycle.)
2) All AC parameters sample tested.

P-Channel Switching Waveforms and Test Circuit



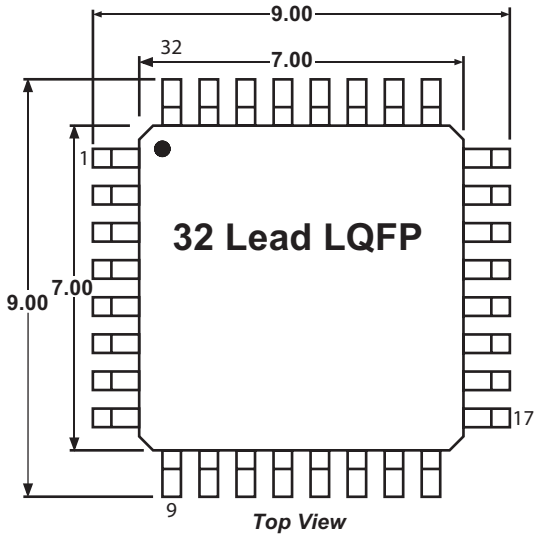
Pin Configuration

Pin	Function	Pin	Function
1	GP1	17	DN6
2	GN1	18	DN3
3	GN2	19	DN5
4	GN3	20	N/C
5	GN6	21	$V_{NN}2$
6	GN5	22	DN2
7	GN4	23	DN4
8	GP4	24	DN1
9	GP5	25	$V_{NN}1$
10	GP6	26	$V_{PP}1$
11	DP6	27	DP1
12	$V_{PP}2$	28	DP2
13	DP5	29	$V_{PP}3$
14	DP4	30	DP3
15	V_{SUB}	31	GP3
16	$V_{NN}3$	32	GP2

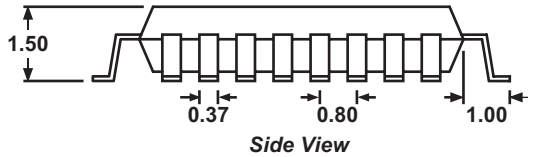
The V_{SUB} pin needs to be connected to the most positive supply

32 Lead Low Quad Flat Pack (LQFP)* Package Outline

All dimensions are in millimeters



Top View

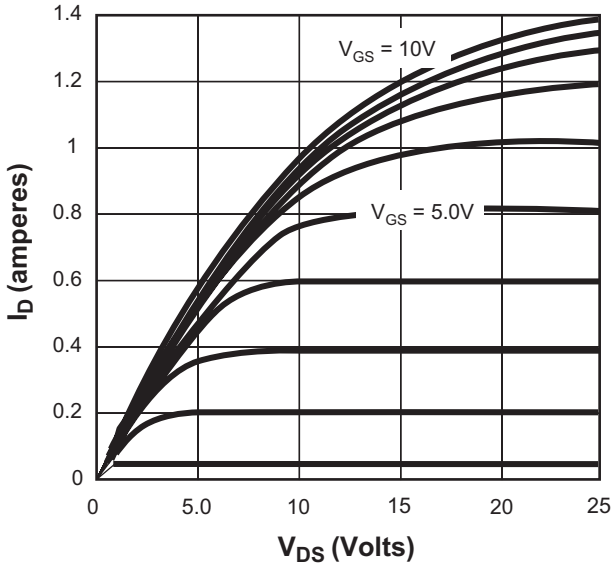


Side View

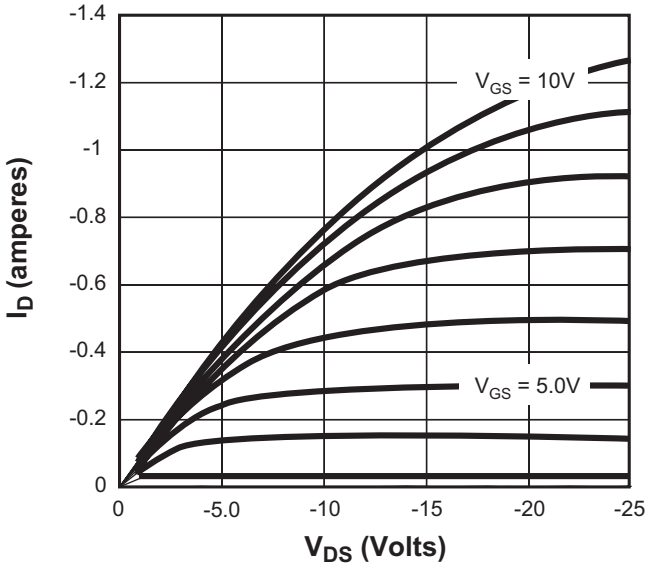
**"Green" certified package*

Typical I-V Characteristics

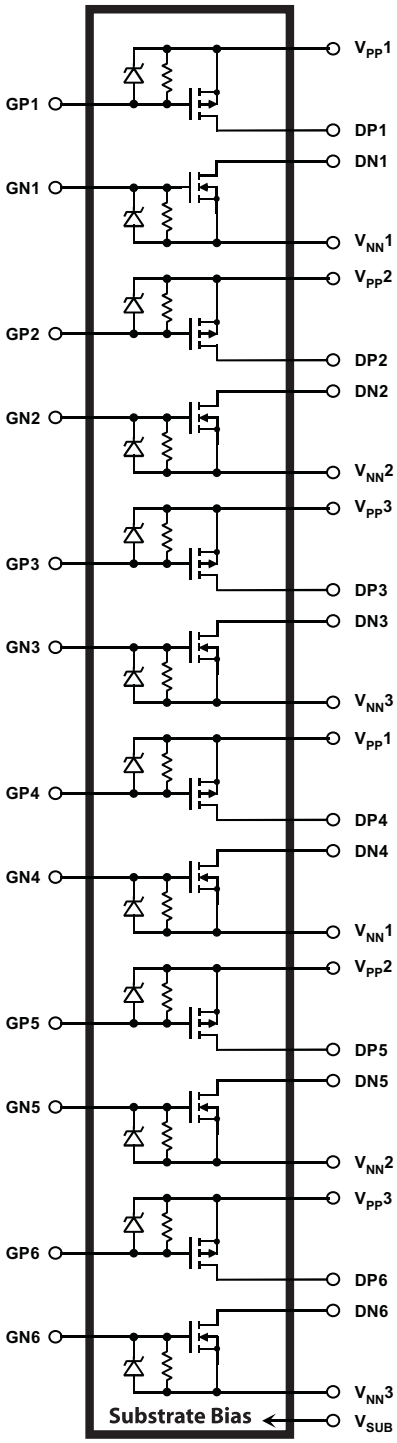
N-Channel



P-Channel



Block Diagram



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